1. A low dielectric constant material having thermal resistance, comprising borazine skeletal molecules shown by the following formula (1), (2), or (3) in an inorganic or organic material molecule.

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$$B=N$$
 $H=N$
 $B=N$
 $B=N$

2. An insulation film between semiconductor layers, comprising the low dielectric constant material having thermal resistance of Claim 1.

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3. A semiconductor device, comprising an insulation film between semiconductor layers comprising the low dielectric constant material having thermal resistance of Claim 1.